



Product Summary

| BV _{DSS} | R bs(on) max | I _D T _A = +25°C |
|-------------------|-------------------------------|--|
| 1001 | $350m\Omega @ V_{GS} = -10V$ | -2.4A |
| -100V | 450mΩ @ V _{GS} = -6V | -2.1A |

Description and Applications

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor controls
- DC-DC converters
- Power management functions
- Relay and solenoid driving

100V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Fast Switching Speed
- Low Input Capacitance
- Low Gate Drive
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZXMP10A17GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

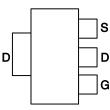
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (63)
- Weight: 0.112 grams (Approximate)

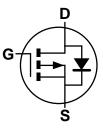
SOT223 (Type DN)



Top View



Pin Out - Top View



Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Baakaga | Packing | | |
|---------------|------------------|---------|-------------|--|
| | Package | Qty. | Carrier | |
| ZXMP10A17GQTA | SOT223 (Type DN) | 1,000 | Tape & Reel | |
| ZXMP10A17GQTC | SOT223 (Type DN) | 4,000 | Tape & Reel | |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

SOT223 (Type DN)

ZXMP10A17 = Product Type Marking Code YWW = Date Code Marking Y = Year (ex: 2 = 2022) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|-----------------|-------------------------------|--------|-------|------|
| Drain-Source Voltage | | V _{DSS} | -100 | V | |
| Gate-Source Voltage | | V _{GS} | ±20 | V | |
| | | (Note 6) | | -2.4 | |
| Continuous Drain Current | $V_{GS} = -10V$ | $T_A = +70^{\circ}C$ (Note 6) | ID | -1.9 | А |
| | | (Note 5) | | -1.7 | |
| Pulsed Drain Current | $V_{GS} = -10V$ | (Note 7) | IDM | -9.4 | А |
| Continuous Source Current | (Body Diode) | (Note 6) | ls | -2.4 | А |
| Pulsed Source Current (Body Diode) (Note 7) | | I _{SM} | -9.4 | А | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|----------|----------------------|-------------|------------|--|
| Power Dissipation | (Note 5) | | 2.0 16 | W mW/°C | |
| Linear Derating Factor | (Note 6) | P _D | 3.9 31 | | |
| Thermal Resistance, Junction to Ambient | (Note 5) | D | 62.5 | | |
| Thermai Resistance, Sunction to Ambient | (Note 6) | R _θ JA | 32.0 | °C/W | |
| Thermal Resistance, Junction to Case | (Note 5) | R _θ JC | 7.7 | | |
| Operating and Storage Temperature Range | | TJ, T _{STG} | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test | Condition |
|--|------------------------|------|-------|-------|------|---|---------------------------------|
| OFF CHARACTERISTICS | 0, | | | | • | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -100 | | _ | V | I _D = -250μA, V _{GS} = 0V | |
| Zero Gate Voltage Drain Current | IDSS | | | -0.5 | μA | V _{DS} = -100V, V | |
| Gate-Source Leakage | I _{GSS} | | | ±100 | nA | $V_{GS} = \pm 20V, V$ | _{DS} = 0V |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | -2.0 | | -4.0 | V | I _D = -250μA, V | _{DS} = V _{GS} |
| Static Drain-Source On-Resistance (Note 8) | | | | 0.350 | Ω | $V_{GS} = -10V, I_{D}$ | = -1.4A |
| Static Drain-Source On-Resistance (Note 8) | R _{DS(on)} | _ | | 0.450 | 12 | $V_{GS} = -6V, I_D =$ | -1.2A |
| Forward Transconductance (Notes 8, 9) | g _{fs} | _ | 2.8 | _ | S | $V_{DS} = -15V, I_{D}$ | = -1.4A |
| Diode Forward Voltage (Note 8) | V _{SD} | _ | -0.85 | -0.95 | V | $I_{S} = -1.7A, V_{GS} = 0V$ | |
| Reverse Recovery Time (Note 9) | t _{RR} | | 33 | _ | ns | I _F = -1.5A, di/dt = 100A/μs | |
| Reverse Recovery Charge (Note 9) | Q _{RR} | | 48 | | nC | | |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | | |
| Input Capacitance | C _{iss} | _ | 424 | _ | pF | V _{DS} = -50V, V _{GS} = 0V f = 1MHz | |
| Output Capacitance | Coss | _ | 36.6 | _ | pF | | |
| Reverse Transfer Capacitance | C _{rss} | _ | 29.8 | _ | pF | | |
| Total Gate Charge (Note 10) | Qg | _ | 7.1 | _ | nC | $V_{GS} = -6.0V$ | |
| Total Gate Charge (Note 10) | Qg | _ | 10.7 | _ | nC | $V_{GS} = -10V$ $V_{DS} = -50V$ $I_{D} = -1.4A$ | |
| Gate-Source Charge (Note 10) | Q _{qs} | _ | 1.7 | _ | nC | | |
| Gate-Drain Charge (Note 10) | Q _{gd} | _ | 3.8 | _ | nC | | |
| Turn-On Delay Time (Note 10) | t _{D(on)} | | 3.0 | | ns | V _{DD} = -15V, V _{GS} = -10V I _D = -1A, R _G ≅ 6.0Ω | |
| Turn-On Rise Time (Note 10) | t _R | _ | 3.5 | _ | ns | | |
| Turn-Off Delay Time (Note 10) | t _{D(off)} | _ | 13.4 | _ | ns | | |
| Turn-Off Fall Time (Note 10) | t _F | _ | 7.2 | _ | ns | | |

5. For a device surface mounted on 25mm x 25mm x 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is Notes: measured when operating in a steady-state condition.

6. Same as Note 5, except the device is measured at t \leq 10 seconds.

7. Same as Note 5, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature.

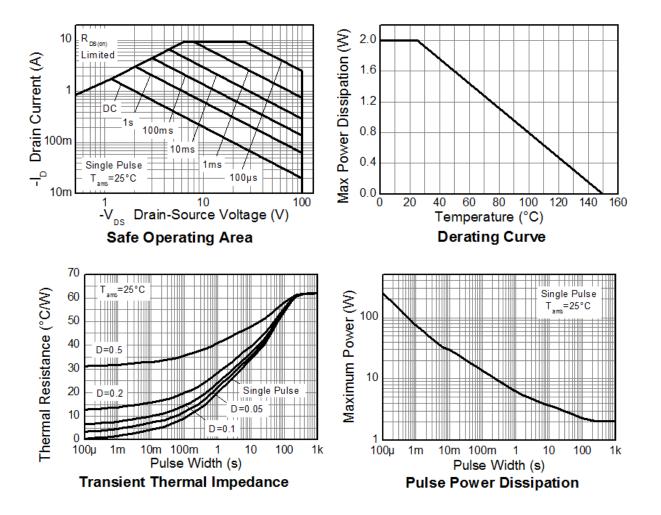
8. Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.

9. For design aid only, not subject to production testing.
10. Switching characteristics are independent of operating junction temperatures.

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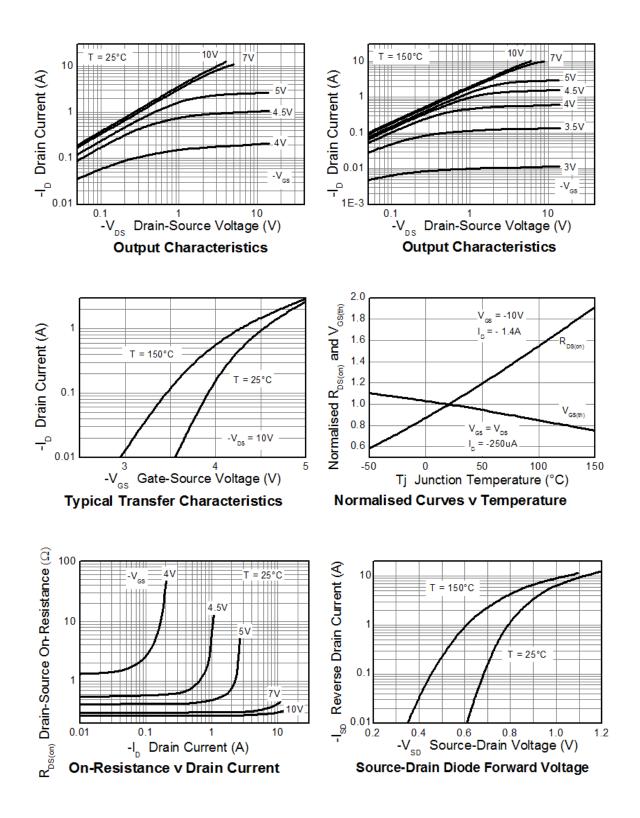


Thermal Characteristics





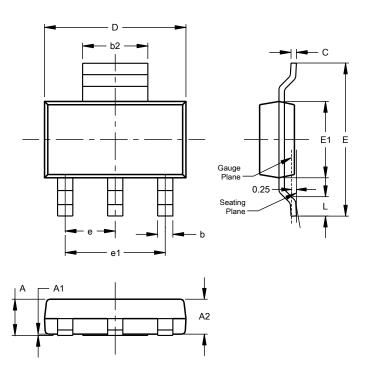
Typical Characteristics (continued)





Package Outline Dimensions

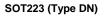
Please see http://www.diodes.com/package-outlines.html for the latest version.



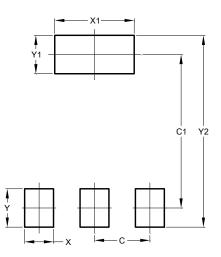
| SOT223 (Type DN) | | | | | |
|------------------|----------------------|---------|------|--|--|
| Dim | Min | Min Max | | | |
| Α | | 1.70 | | | |
| A1 | 0.01 | 0.15 | | | |
| A2 | 1.50 | 1.68 | 1.60 | | |
| b | 0.60 | 0.80 | 0.70 | | |
| b2 | 2.90 | 3.10 - | | | |
| С | 0.20 | 0.32 | | | |
| D | 6.30 | 6.70 | | | |
| E | 6.70 | 7.30 | | | |
| E1 | 3.30 | 3.70 | | | |
| е | | | 2.30 | | |
| e1 | | | 4.60 | | |
| L | 0.85 | | | | |
| All [| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type DN)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| Х | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |



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